Silicon N Channel MOS Type (U-MOSⅢ)/Silicon Epitaxial Schottky Barrier Diode

SSM5H16TU

DC-DC Converter Applications

- 1.8-V drive
- Combined an N-ch MOSFET and a Schottky barrier diode in one package.
- Low R_{DS} (ON) and Low V_F

Absolute Maximum Ratings

MOSFET (Ta = 25°C)

Characteristic		Symbol	Rating	Unit	
Drain-source voltage		V_{DSS}	30	V	
Gate-source voltage		V _{GSS}	± 12	V	
Drain current	DC	I _D	1.9	Α	
	Pulse	I _{DP}	3.8	A	
Drain power dissipation		P _D (Note 1)	0.5	W	
		t = 10s	0.8	VV	
Channel temperature		T _{ch}	150	°C	

Schottky Barrier Diode (Ta = 25°C)

Characteristics	Symbol	Rating	Unit
Reverse voltage	V_{R}	30	V
Average forward current	Io	0.8	Α
Peak one cycle surge forward current	I _{FSM}	6 (50Hz)	Α
Junction temperature	Tj	125	°C

1: GATE 4: CATHODE 2: SOURCE 5: DRAIN 3: ANODE UFV JEDEC — JEITA — TOSHIBA 2-2R1A

Weight: 7 mg (typ.)

MOSFET and Diode (Ta = 25°C)

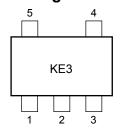
Characteristics	Symbol	Rating	Unit
Storage temperature range	T _{stg}	-55 to 125	°C

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

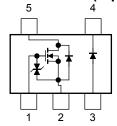
Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1: Mounted on FR4 board (25.4 mm \times 25.4 mm \times 1.6 mm, Cu pad: 645 mm²)

Marking



Equivalent Circuit (top view)



Start of commercial production 2009-09

MOSFET

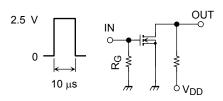
Electrical Characteristics (Ta = 25°C)

Chara	acteristic	Symbol	Test Conditions	Min	Тур.	Max	Unit
Drain-Source breakdown voltage		V _{(BR)DSS}	$I_D = 1 \text{ mA}, V_{GS} = 0 \text{ V}$	30	_		V
		V (BR) DSX	$I_D = 1 \text{ mA}, V_{GS} = -12 \text{ V}$	18	_	_	
Drain cut-off curre	ent	I _{DSS}	V _{DS} = 30 V, V _{GS} = 0 V	_	_	1	μΑ
Gate leakage curi	rent	I _{GSS}	$V_{GS} = \pm 12 \text{ V}, V_{DS} = 0 \text{ V}$	_	_	±1	μΑ
Gate threshold vo	ltage	V _{th}	$V_{DS} = 3 \text{ V}, I_D = 1 \text{ mA}$	0.4	_	1.0	V
Forward transfer	admittance	Y _{fs}	$V_{DS} = 3 \text{ V}, I_D = 1.0 \text{ A}$ (Note 2)	2) 2.0	3.9	_	S
			$I_D = 1.0 \text{ A}, V_{GS} = 4.0 \text{ V}$ (Note 2)	2) —	103	133	
Drain-source ON-resistance	R _{DS (ON)}	$I_D = 0.8 \text{ A}, V_{GS} = 2.5 \text{ V}$ (Note 2)	2) —	125	177	mΩ	
		I _D = 0.5 A, V _{GS} = 1.8 V (Note 2	2) —	165	296		
Input capacitance		C _{iss}			123	_	
Output capacitance		Coss	$V_{DS} = 15V, V_{GS} = 0 V, f = 1 MHz$	_	43	_	pF
Reverse transfer	capacitance	C _{rss}		_	18	_	
Total gate charge Gate-source charge		Qg		_	1.9	_	nC
		Q _{gs}	V _{DS} = 15V, I _D = 1.9 A V _{GS} = 4 V	_	1.1	_	
Gate-drain charge		Q _{gd}	7 43	_	0.8	_	
Switching time	Turn-on time	t _{on}	$V_{DD} = 15 \text{ V}, I_D = 1.0 \text{ A}, \\ V_{GS} = 0 \text{ to } 2.5 \text{ V}, R_G = 4.7 \Omega$	_	9.2		ns
	Turn-off time	t _{off}		_	6.4	_	1115
Drain-source forward voltage		V _{DSF}	$I_D = -1.9 \text{ A}, V_{GS} = 0 \text{ V}$ (Note 2)	2) —	-0.83	-1.2	V

Note 2: Pulse test

Switching Time Test Circuit



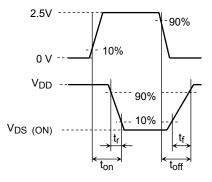


 $V_{DD} = 15 \text{ V}$ $R_G = 4.7 \Omega$

 $Ta = 25^{\circ}C$

Duty≤ 1% V_{IN} : t_r , t_f < 5 ns Common Source (b) V_{IN}

(c) Vout



Precaution

 V_{th} can be expressed as voltage between gate and source when the low operating current value is $I_D = 1$ mA for this product. For normal switching operation, $V_{GS\ (on)}$ requires a higher voltage than V_{th} and $V_{GS\ (off)}$ requires a lower voltage than V_{th} .

(The relationship can be established as follows: $V_{GS\ (off)} < V_{th} < V_{GS\ (on)}$) Be sure to take this into consideration when using the device.

Schottky Barrier Diode

Electrical Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Forward voltage	V _{F (1)}	I _F = 0.1 A	_	0.31	0.36	V
	V _{F (2)}	I _F = 0.2 A	_	0.35	0.4	
	V _{F (3)}	I _F = 0.5 A	_	0.4	0.45	V
	V _{F (4)}	I _F = 0.8 A	_	0.45	0.55	
Reverse current	I _R	V _R = 30 V	_	5.3	50	μА
Total capacitance	C _T	V _R = 0 V, f = 1 MHz	_	120	_	pF

Precaution

The Schottky barrier diode in this device has large reverse current leakage compared to typical switching diodes. Thus, excessive operating temperature or voltage may cause thermal runaway. To avoid this problem, be sure to take both forward and reverse loss into consideration.

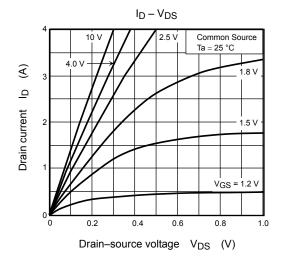
Handling Precaution

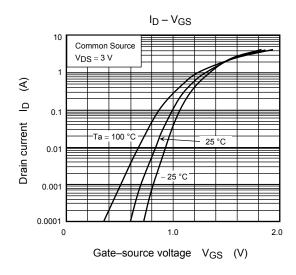
When handling individual devices (which are not yet mounted on a circuit board), ensure that the environment is protected against static electricity. Operators should wear anti-static clothing, and containers and other objects that come into direct contact with devices should be made of anti-static materials.

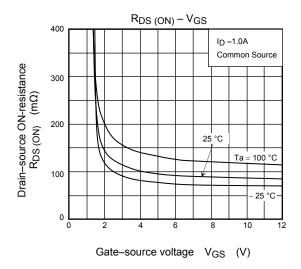
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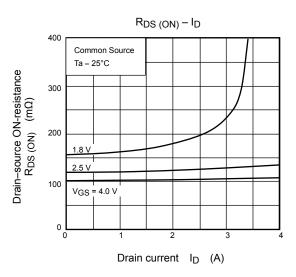
Thermal resistance $R_{th\ (j-a)}$ and drain power dissipation P_D vary depending on board material, board area, board thickness and pad area. When using this device, please take heat dissipation into consideration.

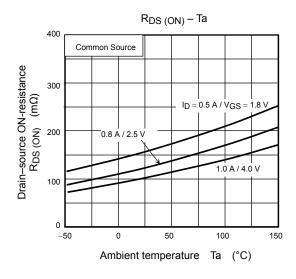
MOSFET

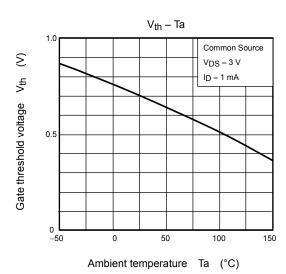




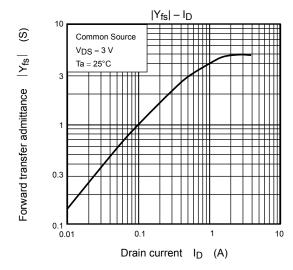


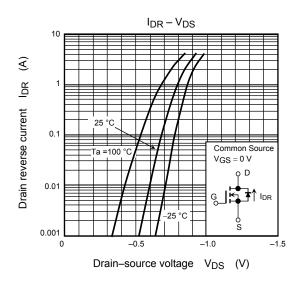


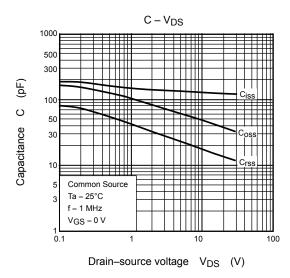


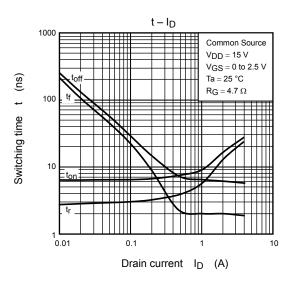


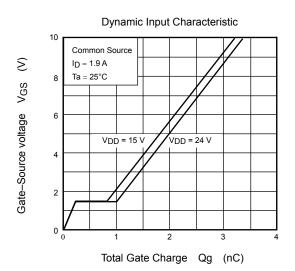
MOSFET



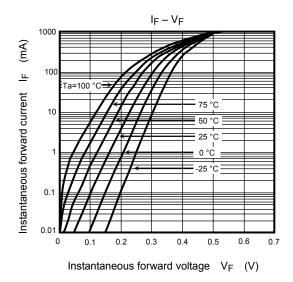


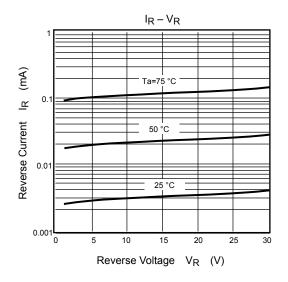


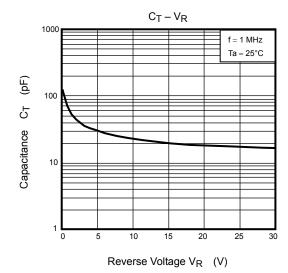




Schottky Barrier Diode







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